

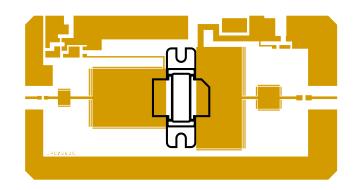
L-Band, GaN/SiC, RF Power Module

 $960 - 1220 \; MHz \; | \; 2900 \; W \; typ \; | \; 70\% \; Efficiency \; typ \; | \; \; 21dB \; Gain \; typ \; | \; 75V \; | \; \; 24 \; x \; (3.5 \mu s \; on, \; 11 \mu s \; off) \; Pulse \; Length, \; \; 1.1\% \; LTDC \; | \; 100 \; Hz \; | \; 100 \; Hz$

IGNP0912M2400 is a high power GaN-on-SiC RF power module that has been designed to suit the unique needs of TACAN systems. Under 24 x (3.5 μ s on, 11 μ s off), LTDC =1.1% duty cycle pulse conditions, it supplies a minimum of 2400 W of peak output power, with typically 20.5dB of associated gain and 65% efficiency. It operates from a 75V supply voltage.

FEATURES

- GaN on SiC HEMT Technology
- Output Power >2400 W
- 100% RF Tested under 24 x (3.5μs on, 11μs off), LTDC =1.1% pulse conditions



APPLICATIONS

TACAN and DME Systems

Table 1. RF Electrical Characteristics (Case temperature = 30 °C unless otherwise stated)

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Gain	G	19	20.5	22	dB	P _{out} = 2400W
Drain Efficiency	η	62	65	75	%	f = 960, 1090, 1215 MHz
Pulse Droop	D	-0.4	-0.2	0.2	dB	24 x (3.5μs on, 11μs off), LTDC =1.1%
Input Return Loss	IRL	8	15	24	dB	
Load Mismatch Stability	VSWR-S	2:1				$V_{ds} = 75V, I_{DS} = 100mA$
VSWR Withstand	VSWR-LMT	3:1				

Note 1: Consult Integra Technologies Application Note 001 for information on how RF output power and pulse droop are measured.

Table 2. DC Electrical Characteristics (Case temperature = 25 °C unless otherwise stated)

Parameter	Symbol	Min	Тур	Max	Units	Test Conditions
Gate Pinch-Off Voltage	V _P	-5.0			V	$V_{DS} = 75V, I_{DS} = 1mA$
Quiescent Gate Voltage	V _Q		-2.9		V	V _{DS} = 75V, I _{DS} = 100mA



Table 3. Absolute Maximum Ratings (Not Simultaneous)

Parameter	Symbol	Value	Units	Test Conditions
DC Drain-Source Voltage	V _{DS}	300	V	25 °C
DC Gate-Source Voltage	V _{GS}	-8 to +1.0	V	25 °C
DC Drain Current	I _D	98	А	25 °C
DC Gate Current	I _G	9.8	mA	25 °C
RF Input Power	P _{RF,IN}	35	W	25 °C
Operating Channel Temperature	Т _{сн}	-55 to +225	°C	
Storage Temperature	T _{stg}	-62 to +150	°C	
Soldering Temperature	T _{SOLDER}	260 for 60s	°C	

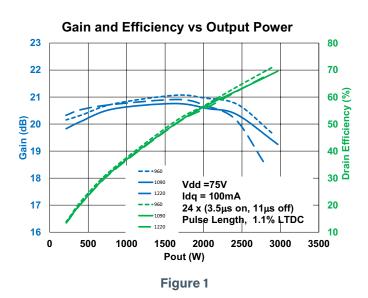
Note: Operation outside the limits given in this table may cause permanent damage to the transistor

Table 4. Thermal Resistance (Case temperature = 85 °C unless otherwise stated)

Parameter	Symbol	Тур	Units	Test Conditions
Peak Thermal Resistance, Channel to Case	R _{TH}	0.1	°C/W	$P_{\rm diss}$ = 1292W $V_{\rm DS}$ = 75V 24 x (3.5μs on, 11μs off), LTDC =1.1%



TYPICAL PERFORMANCE



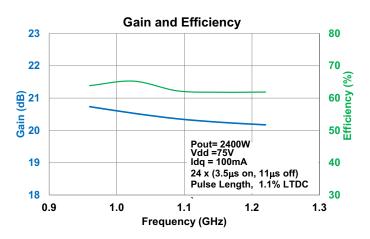


Figure 2

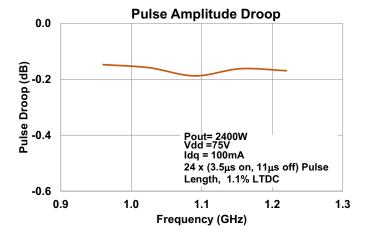
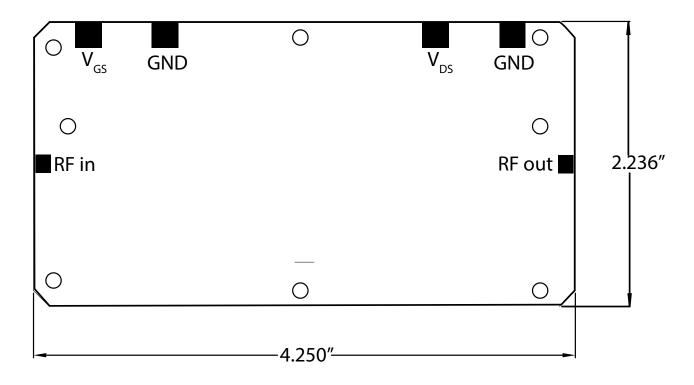
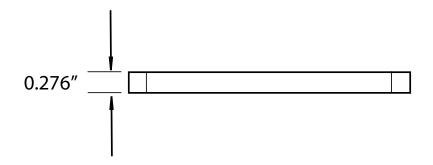


Figure 3



MECHANICAL DIMENSIONS







ESD & MSL Rating

Parameter	Rating	Standard		
ESD Human Body Model (HBM)	TBD	ESDA/JEDEC JS-001-2012		
ESD Charged Device Model (CDM)	TBD	JEDEC JESD22-C101F		
Moisture Sensitivty Level (MSL)	Unlimited Shelf Life	IPC/JEDEC J-STD-020		

REACH Compliance

Integra Technologies supports EU Regulation number 1907/2006 concerning the Registration, Evaluation, Authorization, and Restriction of Chemicals (REACH) as these apply to Integra semiconductor products, development tools, and shipping packaging.

In support of the REACH regulation, Integra will:

- •Inform customers and recipients of Integra product if they contain any substances that are of very high concern (SVHC) per the European Chemical Agency (ECHA) website.
- •Notify ECHA if any Integra product that contains any SVHCs which exceed guidelines for REACH chemicals by weight per part number and for total content weight per year for all products produced in or imported to the European market.
- Cease shipments of product containing REACH Annex XIV substances until authorization has been obtained.
- •Cease shipment of product containing REACH Annex XVII chemicals when restrictions apply.

Integra has evaluated its materials, BOMs, and product specifications and product and has determined that this transistor conforms to all REACH and SVHC regulations and guidelines. Integra has implemented actions and control programs that will assure continued compliance.

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DEFINITIONS:

DATA SHEET STATUS

Advanced Specification - This data sheet contains Advanced specifications.

Preliminary Specification - This data sheet contains specifications based on preliminary measurements and data.

Final Specification - This data sheet contains final product specifications.

MAXIMUM RATINGS Stress above one or more of the maximum ratings may cause permanent damage to the device. These are maximum ratings only operation of the device at these or at any other conditions above those given in the characteristics sections of the specification is not implied. Exposure to maximum values for extended periods of time may affect device reliability.

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